Synthesis and Characterization of TiO$_2$ Semiconductor Doped by AgNO$_3$ and Their Application as Photoanode in Dye-sensitized Solar Cells

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Abstract
The use of Titanium dioxide (TiO$_2$) semiconductors in Dye-Sensitized Solar Cells (DSSC) devices have been extensively studied and synthesized with various techniques to obtain optimal performance. The TiO$_2$ semiconductors with optimal performance are influenced by the growth method, the time of growth, the shape of the microstructure, and the optical properties. In this study, it was reported about the effect of silver nanoparticles (AgNO$_3$) doping onto TiO$_2$ semiconductors on their microstructure, reflectance, and efficiency of the DSSC device. The synthesis of TiO$_2$ was carried out using liquid phase deposition (LPD) and immersed into an AgNO$_3$ solution with a variation of time namely 0.5 h, 1 h, 2 h, 4 h, and 6 h. The entire TiO$_2$ + AgNO$_3$ sample, then used as a photoanode on DSSC with plastisol as a counter electrode. Characterization of microstructure, reflectance, and DSSC performance was carried out by using field emission scanning electron microscopy (FESEM), Uv-Vis Spectrophotometer, and Gamry Instrument, respectively. The FESEM results show that AgNO$_3$ has successfully grown on the ITO substrate in a spherical shape with an average particle diameter ranging from 1.52-2.29 μm. From observations using the Uv-Vis Spectrophotometer, obtained the energy band gap values ranged from 0.22 to 2.27 eV. The best results of DSSC device efficiency, with TiO$_2$+AgNO$_3$/Dye/Plastisol structure, have resulted in the Voc of 0.694 V, current density (Jsc) of 0.943 mA/cm$^2$ and fill factor (FF) of 43.50% which is obtained at sample 1.


INTRODUCTION
The energy crisis in the current technological era is one of the challenges that is being faced and needs efforts to develop alternative energy. One of the alternative energy that has a potential source but has not been maximally utilized is energy comes from sunlight. To harness energy from sunlight is through a device known as a solar cell. Solar cells work by directly converting solar radiation into electricity. The widely used solar cells are silicon-based which are the result of the rapid development of electronic semiconductor technology. Solar cells dominated by silicon have a disadvantage especially the cost of synthesis is more expensive than fossil energy sources. Besides, during the synthesis...
process, there is the use of hazardous chemicals (Zamrani et al., 2013). With these weaknesses, the researchers are trying to develop solar cells to replace silicon-based solar cells, such as DSSC (M. I. A. Umar et al., 2017). DSSC has the advantage of not requiring high purity semiconductor materials so that the production costs are relatively low (Septina, 2007), and the manufacturing process does not use chemicals that are dangerous and environmentally friendly.

The most widely used semiconductor in DSSC devices is TiO$_2$ and Zinc Oxide (ZnO) because they have a wide bandgap. ZnO is a semiconductor that has a fairly wide bandgap of 3.37 eV (Kao et al., 2007), while on TiO$_2$, it has a bandgap energy of 3.2 eV (Asahi et al., 2001). At present, the use of TiO$_2$ as a semiconductor has been widely developed because it can provide better efficiency, inexpensive, photo corrosion resistance, and has good optical characteristics (Grätzel, 2003). TiO$_2$ semiconductors that are used today have been developed by modification through the addition of metal or doping in small amounts that can change the material properties (M. I. A. Umar, 2019). One of the metals that are widely added to the synthesis of TiO$_2$ nanoparticles is to use silver nitrate (AgNO$_3$). The AgNO$_3$ doping also aims to reduce pore size, and broaden the surface of the catalyst so that it can optimize the activity of TiO$_2$. Besides doping AgNO$_3$ nanoparticles on TiO$_2$, causing changes in the characterization of TiO$_2$ particles such as size, and particle morphology (Das et al, 2009). The size and shape of TiO$_2$ nanoparticles are very important in determining the optical, electrical, magnetic, and semiconductor catalysts of TiO$_2$. Factors that can affect particle size in synthesis are solution temperature, solution concentration (Silkeikaitė et al., 2006).

Generally, TiO$_2$ has three phases namely rutile, anatase, and brookite (Mo et al., 1995). Anatase TiO$_2$ crystals have more active than rutile. The anatase phase is considered the most favorable phase for photocatalyst and solar energy conversion (Ekasari et al., 2013). The use of TiO$_2$ with the anatase phase in its application to DSSC has the potential to achieve higher efficiency. Based on the synthesis process carried out for 1 hour by precipitating a growth solution for 24 hours, it can produce a semiconductor TiO$_2$ with an anatase phase that has a high dielectric constant ($\varepsilon = 80$) and the size of the nanoparticles between 14-16 nm (Ekasari & Yudoyono, 2013). Treatment with the addition of AgNO$_3$ doping onto the TiO$_2$ film with variations in growth time may promise to change the resulting semiconductor characterization. This is proven by FESEM results showed that the presence of silver nanoparticles on an ITO substrate in a spherical shape with particle diameters ranging from 1.52-2.29 μm. Uv-Vis spectrophotometer also provides data on the value of the energy bandgap or bandgap ranging from 0.22 to 2.27 eV. Besides that, the achievements of DSSC devices were also analyzed using AgNO$_3$-supported TiO$_2$ as photo-anode which are discussed in detail in the results and discussion section.

**METHOD**

**Material and characterization**

The main chemicals used include silver nitrate (AgNO$_3$) as doping, boric acid (H$_3$BO$_3$), and Potassium Titanyl Phosphate (KTP / KTiOPO$_4$) as precursors. The use of plastisol as the main material in the manufacture of counter electrodes (CE). All of this research material was purchased from Sigma-Aldrich and used directly without prior purification. The research equipment used includes Spin-coater, Uv-Vis Spectrophotometer, and Field Emission Scanning Electron Microscope (FESEM) and Gamry Instrument.

**Synthesis Procedure of TiO$_2$ + AgNO$_3$**

To conduct the synthesis process, we used the substrate, and bottles used have been cleaned first. In the TiO$_2$ synthesis process, the addition of silver nitrate (AgNO$_3$) in the form of small white beads is used. The addition of silver particles is carried out utilizing
AgNO₃ reduction with H₃BO₃ and KTP. AgNO₃ nanoparticle growth was carried out by varying the effect of time by making a solution with the following steps, as much as 0.0136 grams of AgNO₃ mixed with 4 mL of Deionized Water (DI), as much as 0.124 gr H₃BO₃ yang mixed with 20 mL DI, 0.6 gr KTP yang mixed with 20 mL DI. These three solutions were mixed and put the substrate which had grown by TiO₂ into these solutions with a variations growth time of 0.5 h, 1 h, 2 h, 4 h, and 6 h. The TiO₂ nanoparticles were first grown using the Liquid Phase Deposition (LPD) method. This method grows TiO₂ nanoparticles in a wise bath with a temperature of 80° C. After reaching the specified time, the substrate is dried and Annealing for 4 hours at 400° C. The complete procedure on the method of growing TiO₂ has been well described by previous researchers (A. A. Umar et al., 2018).

Counter electrodes (CE) were synthesized using the spin coating method. This method grows platinum (Pt) on the substrate by placing the substrate on the Spin-coater and then dripping with 1 mL plastisol. Then spin with a speed of 1500 rpm and put into Petri dish which has been wrapped in aluminum foil and heated on a hot plate for 15 minutes. This process is carried out 3 times to get a thick layer of platinum. After that, annealing in the furnace for 1 hour at 400° C.

RESULTS AND DISCUSSION

Fig. 1 shows the microstructure shape of resultant TiO₂ obtained from the FESEM image at a magnification of 5000 times with variations in the time of preparation of growth for each sample that is 0.5, 1, 2, 4 and 6 hours. In Fig. 1, the difference in FESEM results obtained from the TiO₂ film without doping (a) and (b-f) TiO₂ with AgNO₃ doping with variations in growth time.

Figure 1. FESEM of (a) TiO₂, (b-f) by doping AgNO₃ with variations in growth time from 0.5 h, 1 h, 2 h, 4 h, and 6 h (Scale-bar is 4 µm).
Based on the analysis of Fig. 1b-1f, it also shows that AgNO₃ nanoparticles have spherical morphology. The growth distribution of AgNO₃ nanoparticles formed is more bad-aligned with increasing growth time, evidenced by the presence of several gaps that are not overgrown by nanoparticles. All particles have a porous structure, with sizes ranging from 0.82 μm to 2.24 μm, which is useful in absorbing dye molecules to optimize the excitation of electrons if used on DSSC (Irmansyah et al., 2008; Nadaek et al., 2012). The absorption value is increase with the concentration of silver nanoparticles in the film increased (Masakke et al., 2015).

This non-uniform particle shape can be caused by high temperatures. This is in line with previous research (Fatimah et al., 2014), which says that "this inhomogeneity is due to the presence of sintering, which is the crystal clustering due to high heating". This was shown in the previous research which said that the increase in growth time would affect particle size, where increasing the growth time the make the particle size also increased (Distyawan et al., 2013).

Table 1. Diameter and surface area of TiO₂ particles

<table>
<thead>
<tr>
<th>Name</th>
<th>Diameter Range (μm)</th>
<th>Average Surface Area (μm²)</th>
<th>Number of Particles</th>
<th>Density (number / area (μm²))</th>
</tr>
</thead>
<tbody>
<tr>
<td>Sample 1</td>
<td>1.70 ± 0.53</td>
<td>8.58 ± 2.68</td>
<td>81</td>
<td>9.44</td>
</tr>
<tr>
<td>Sample 2</td>
<td>1.53 ± 0.54</td>
<td>8.44 ± 2.97</td>
<td>74</td>
<td>8.77</td>
</tr>
<tr>
<td>Sample 3</td>
<td>2.29 ± 0.67</td>
<td>9.95 ± 2.89</td>
<td>72</td>
<td>7.24</td>
</tr>
<tr>
<td>Sample 4</td>
<td>1.62 ± 0.48</td>
<td>9.35 ± 2.77</td>
<td>68</td>
<td>7.27</td>
</tr>
<tr>
<td>Sample 5</td>
<td>1.52 ± 0.50</td>
<td>8.65 ± 2.87</td>
<td>61</td>
<td>7.05</td>
</tr>
</tbody>
</table>

The surface area of the TiO₂ particles seen in Table 1. It shows that the surface area of the particles at the time of growth was 0.5 h and 1 h smaller than the other samples. Whereas in 2 hours, it has the biggest surface area. The difference in growth time given affects the size of TiO₂ particles that are formed. At 0.5 h the particle size was relatively stable, this can be seen in sample 1 having an average surface area of 8.58 ± 2.68 μm². While at one hour the size of the particle area was reduced to 8.44 μm² ± 2.97 μm². The increase in growth time will affect the number of silver nanoparticles that are grown. We have used time variations to the growth of silver nanoparticles, which were 0.5 h, 1 h, 2 h, 4 h, and 6 h. The time variation is used to determine the number of nanoparticles that are formed in each sample. It is also used to determine the density of the number of nanoparticles formed in TiO₂. This is in line with previous studies that used growth time at 0.5 h. Growth reaction continued with the peak reaction of silver nanoparticle formation continued until the 60 and 90 minutes (Masakke & Rasyid, 2015). Concerning the amount of TiO₂ nanoparticles formed, this will affect the growth density of TiO₂ nanoparticles. For the level of density of growth of particles. In sample 1 the density level reached 9.44 / μm² as well as the sample with the highest density value.

Fig. 2 shows the graph of the wavelength (λ) and the % R (reflectance) values obtained from the Uv-Vis spectrophotometer. The output data from the Uv-Vis spectrophotometer will produce %R values that vary between each sample. After the % R-value is obtained, this is used to determine the parameter values of R, (1-R)², 2R, α, hv, and αhv. These parameters are used to determine the value of the bandgap energy. After the αhv² parameter values are obtained, the two parameters are then plotted into a graph of αhv² values. Horizontal linear lines are drawn and vertical linear lines from the graph are drawn. At a certain point in the linear line that has been drawn there is an intersection...
point. This intersection point is called \( \alpha \). \( \alpha \) values are obtained using the Kubelka-Munk equation (Karim et al., 2016). The value of the ordinate point \( \alpha \) from sample 1 to sample 5 can be seen in Table 2.

![Graphs showing TiO\(_2\) bandgap energy](image)

Figure 2. The \( \alpha \) values for each sample (a) Sample 1, (b) Sample 2, (c) Sample 3, (d) Sample 4 and (e) Sample 5.

Table 2. The TiO\(_2\) bandgap energy as an effect of AgNO\(_3\) doped at the various growth time applications.

<table>
<thead>
<tr>
<th>No</th>
<th>Name</th>
<th>Energy Band Gap Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>Sample 1</td>
<td>2.27 eV</td>
</tr>
<tr>
<td>2</td>
<td>Sample 2</td>
<td>1.08 eV</td>
</tr>
<tr>
<td>3</td>
<td>Sample 3</td>
<td>0.84 eV</td>
</tr>
<tr>
<td>4</td>
<td>Sample 4</td>
<td>0.47 eV</td>
</tr>
<tr>
<td>5</td>
<td>Sample 5</td>
<td>0.22 eV</td>
</tr>
</tbody>
</table>

The addition of AgNO\(_3\) affects the gap value of the TiO\(_2\) semiconductor energy band. This is similar to what was said by Cheng et al. (2016), "Doping significantly influences the absorption of light and bandgap energy". In sample 1 by growing TiO\(_2\) by
doping AgNO₃ it has an energy band gap value of 2.27 eV, making electrons easier to move because the gap that is jumped is not too wide.

The results of the efficiency testing of the TiO₂ application in DSSC using the Gamry Instrument with TiO₂+AgNO₃/Dye/Plastisol structure are shown in Fig. 2. The details of the photovoltaic parameters of the DSSC performance with TiO₂ as photoanode are shown in Table 3. In sample 1 with a bandgap energy of 2.27 eV, resulting in the electrons can absorb photons better than other samples, resulting in the best efficiency. These results are similar to those shown in Table 3 data.

Table 3. The photovoltaic data of DSSC devices with TiO₂+AgNO₃/Dye/Plastisol structure.

<table>
<thead>
<tr>
<th>Sample Name</th>
<th>Jsc (mA/cm²)</th>
<th>Eff (%)</th>
<th>FF</th>
<th>Voc (mV)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Sample 1</td>
<td>0.943</td>
<td>0.285</td>
<td>0.435</td>
<td>0.694</td>
</tr>
<tr>
<td>Sample 2</td>
<td>0.825</td>
<td>0.227</td>
<td>0.446</td>
<td>0.616</td>
</tr>
<tr>
<td>Sample 3</td>
<td>0.657</td>
<td>0.201</td>
<td>0.431</td>
<td>0.706</td>
</tr>
<tr>
<td>Sample 4</td>
<td>0.531</td>
<td>0.148</td>
<td>0.463</td>
<td>0.599</td>
</tr>
<tr>
<td>Sample 5</td>
<td>0.553</td>
<td>0.098</td>
<td>0.363</td>
<td>0.488</td>
</tr>
</tbody>
</table>

Figure 3. The J-V graph of DSSC devices with the structure of TiO₂+AgNO₃/Dye/Plastisol.

There was a very significant change in the value of the current density (Jsc) of each sample. The highest Jsc value was found in sample 1 which is equal to 0.943 mA/cm². The efficiency in sample 1 is the highest compared to others. The DSSC performance decreases with increasing in AgNO₃ growth time. The best DSSC performance with the use of TiO₂ as a photoanode doped by silver nanoparticles is 2.85 x 10⁻¹%. This efficiency result is 140 times greater than Anita et al. (2013), by using chlorophyll long bean leaves as a dye with a conversion efficiency of 2 x 10⁻⁴%. But this performance is still far smaller compared to Grätzel (2003), by using a synthetic dye which reaches 11%.
CONSLUSSION

There is an influence of the TiO$_2$ microstructure formed with variations of growth time for 0.5 h, 1 h, 2 h, 4 h, and 6 h. The nanoparticles formed have a spherical microstructure with almost the same shape in each sample. The longer the growth time of TiO$_2$ nanoparticles by doping AgNO$_3$, the greater the size of the nanoparticles formed. This is in line with the number of nanopores formed on TiO$_2$ nanoparticles. With the least nanopores formed, the absorption of dye will be less, resulting in the efficiency of DSSC devices also decreases. This statement also in line with the band gap energy were decrease with the increase of AgNO$_3$ growth time.

The most optimum DSSC device performance is 0.285% with an open voltage (Voc) of 0.694 V, current density (Jsc) of 0.943 mA / cm$^2$, and a fill factor (FF) of 43.50% produced by the first sample as photoanode on the DSSC device.

ACKNOWLEDGMENTS

This work has been carried out with the financial support of the Malaysian Ministry of Higher Education (MOHE). The author would like to acknowledge Dr. H. Kasmuri, M.A, Dra. Desmita, M.Si., Dr. H. Rizal, M. Ag. The author also acknowledges Bundo Hj. Cherana, Miftahul Farid Rafi Marjoni Imamora for support in this work.

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